



Standard Test Method for Electrical Performance of Photovoltaic Cells Using Reference Cells Under Simulated Sunlight¹

This standard is issued under the fixed designation E948; the number immediately following the designation indicates the year of original adoption or, in the case of revision, the year of last revision. A number in parentheses indicates the year of last reapproval. A superscript epsilon (ϵ) indicates an editorial change since the last revision or reapproval.

1. Scope

1.1 This test method covers the determination of the electrical performance of a photovoltaic cell under simulated sunlight by means of a calibrated reference cell procedure.

1.2 Electrical performance measurements are reported with respect to a select set of standard reporting conditions (SRC) (see [Table 1](#)) or to user-specified reporting conditions. In either case, the chosen reporting conditions are abbreviated as RC.

1.2.1 The RC include the cell temperature, the total irradiance, and the reference spectral irradiance distribution.

1.3 This test method is applicable only to photovoltaic cells with a linear short-circuit current versus total irradiance response up to and including the total irradiance used in the measurement.

1.4 The cell parameters determined by this test method apply only at the time of test, and imply no past or future performance level.

1.5 The values stated in SI units are to be regarded as standard. No other units of measurement are included in this standard.

1.6 *This standard does not purport to address all of the safety concerns, if any, associated with its use. It is the responsibility of the user of this standard to establish appropriate safety and health practices and determine the applicability of regulatory limitations prior to use.*

2. Referenced Documents

2.1 ASTM Standards:²

[E490 Standard Solar Constant and Zero Air Mass Solar Spectral Irradiance Tables](#)

[E491 Practice for Solar Simulation for Thermal Balance](#)

¹ This test method is under the jurisdiction of ASTM Committee E44 on Solar, Geothermal and Other Alternative Energy Sources and is the direct responsibility of Subcommittee E44.09 on Photovoltaic Electric Power Conversion.

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² For referenced ASTM standards, visit the ASTM website, www.astm.org, or contact ASTM Customer Service at service@astm.org. For *Annual Book of ASTM Standards* volume information, refer to the standard's Document Summary page on the ASTM website.

Testing of Spacecraft

[E691 Practice for Conducting an Interlaboratory Study to Determine the Precision of a Test Method](#)

[E772 Terminology of Solar Energy Conversion](#)

[E927 Specification for Solar Simulation for Photovoltaic Testing](#)

[E973 Test Method for Determination of the Spectral Mismatch Parameter Between a Photovoltaic Device and a Photovoltaic Reference Cell](#)

[E1125 Test Method for Calibration of Primary Non-Concentrator Terrestrial Photovoltaic Reference Cells Using a Tabular Spectrum](#)

[E1362 Test Methods for Calibration of Non-Concentrator Photovoltaic Non-Primary Reference Cells](#)

[G173 Tables for Reference Solar Spectral Irradiances: Direct Normal and Hemispherical on 37° Tilted Surface](#)

3. Terminology

3.1 *Definitions*—Definitions of terms used in this test method may be found in Terminology [E772](#) and in Specification [E927](#).

3.2 Definitions of Terms Specific to This Standard:

3.2.1 *effective irradiance, n*—the irradiance that a solar simulator produces as measured by a cell's short-circuit current relative to a reference value for the cell's short-circuit current at a particular RC.

3.2.1.1 *Discussion*—This reference value typically corresponds to a different spectral irradiance distribution than the solar simulator.

3.2.2 *reporting conditions, RC, n*—the reference spectral irradiance distribution, total irradiance, and cell temperature to which the photovoltaic current-voltage performance is measured and corrected.

3.2.3 *test cell, n*—the photovoltaic cell to be tested, or cell under test, using the method described herein.

3.3 *Symbols*—The following symbols and units are used in this test method:

3.3.1 O —as a subscript, denotes a value under the specified RC.

3.3.2 A —area of the test cell, (m^2).

3.3.3 A_R —area of the reference cell, (m^2).

TABLE 1 Standard Reporting Conditions

Reference Spectral Irradiance Distribution	Total Irradiance, E_0 (Wm^{-2})	Cell Temperature, T_0 ($^{\circ}\text{C}$)
Tables G173 Direct Normal	900	25
Tables G173 Hemispherical	1000	25
Tables E490	1366.1	25

3.3.4 C_R —calibration constant of reference cell, (Am^2W^{-1}).

3.3.5 C_T —transfer calibration ratio, (dimensionless).

3.3.6 E —total irradiance, Wm^{-2} .

3.3.7 FF —fill factor, (%).

3.3.8 I —current of the test cell (A).

3.3.9 I_{MP} —current of the test cell at maximum power in the power-producing quadrant (A).

3.3.10 I_{SC} —short-circuit current of the test cell (A).

3.3.11 $I_{SC,R}$ —short-circuit current of the reference cell (A).

3.3.12 $I_{SC,M}$ —short-circuit current of the monitor cell (A).

3.3.13 M —spectral mismatch parameter (dimensionless).

3.3.14 P_{MP} —maximum power of the test cell in the power-producing quadrant (W).

3.3.15 R_S —series resistance of the test cell (Ω).

3.3.16 S —current correction factor due to spatial non-uniformity of irradiance (dimensionless).

3.3.17 T —temperature of the test cell ($^{\circ}\text{C}$).

3.3.18 T_R —temperature of the reference cell ($^{\circ}\text{C}$).

3.3.19 U_0 —ordered set of test cell current, voltage, and power values at RC (A, V, W).

3.3.20 V —voltage of the test cell (V).

3.3.21 V_{MP} —voltage of the test cell at maximum power in the power-producing quadrant (V).

3.3.22 V_{OC} —open-circuit voltage of the test cell (V).

3.3.23 η —efficiency (%).

4. Summary of Test Method

4.1 The performance test of a photovoltaic cell consists of measuring the electrical current versus voltage (I-V) characteristic of the cell while illuminated by a solar simulator and with its temperature sufficiently controlled.

4.2 A calibrated photovoltaic reference cell (see 6.1) is used to determine the effective irradiance during the test.

4.3 Simulated sunlight is used for the electrical performance measurement, and solar simulation requirements are defined in Specification **E927** (terrestrial applications) and Practice **E491** (space applications).

4.4 The data from the measurements are corrected to the desired RC. Three possible SRC are defined in **Table 1**.

4.4.1 Measurement error in test cell current caused by deviations of the irradiance conditions from the RC is corrected using the effective irradiance measured with the reference cell and the spectral mismatch parameter, M , which is determined in accordance with Test Method **E973**.

4.4.1.1 This test method does not apply corrections to cell voltage for irradiance deviations, thus the solar simulator irradiance must be sufficiently well controlled to accurately determine other parameters under RC, especially maximum power and open-circuit voltage. To this end, the effective irradiance during the measurement is restricted to be within $\pm 2\%$ of the RC irradiance. However, there will still be measurement uncertainty due to irradiance variations in this range.

4.4.2 Measurement error caused by deviation of the test-cell and reference-cell temperatures from the RC is minimized by maintaining the cell temperatures sufficiently close to the required RC value. To this end, the test cell temperature during the measurement is restricted to be within $\pm 1^{\circ}\text{C}$ of the RC temperature.

4.4.2.1 Test Method **E973** provides for correction of test cell current through a temperature-dependent spectral mismatch parameter, $M(T)$; however, Test Method **E973** allows the temperature correction to be bypassed if the temperature is within $\pm 1^{\circ}\text{C}$.

4.4.2.2 This test method does not apply corrections to cell voltage for temperature deviations, thus the test-cell temperature must be sufficiently well controlled to accurately determine other parameters under RC, especially maximum power and open-circuit voltage. However, there will still be measurement uncertainty due to temperature variations in this range.

4.4.3 The measurement procedure employs a reference cell-test cell substitution technique that is designed to minimize errors in short-circuit current caused by spatial non-uniformity of the solar simulator irradiance. A correction for spatial non-uniformity of irradiance may be applied to measured current data if the reference cell and test cell have different areas; the correction is defined as the ratio of the effective irradiance in the solar simulator over the area of the test cell to the effective irradiance over the area of the reference cell.

5. Significance and Use

5.1 This test method provides a procedure for testing and reporting the electrical performance of photovoltaic cells.

5.2 The test results may be used for comparison of cells among a group of similar cells or to compare diverse designs, such as different manufacturers' products. Repeated measurements of the same cell may be used to study changes in device performance.

5.3 This test method determines the electrical performance of a photovoltaic cell at a single instant of time and the results do not imply any past or future performance.

5.4 This test method requires a linear reference cell calibrated with respect to an appropriate reference spectral irradiance distribution, such as Tables **E490**, or **G173**. It is the responsibility of the user to determine which reference spectral irradiance distribution is appropriate for a particular application.

6. Apparatus

6.1 *Reference Cell*—A linear, calibrated, photovoltaic solar cell used to determine the total irradiance during the electrical performance measurement.

6.1.1 Reference cells may be calibrated in accordance with Test Methods E1125 or E1362, as is appropriate for a particular application.

NOTE 1—No reference cell calibration standards presently exist for space applications, although procedures using high-altitude balloon and low-earth orbit flights are being used to calibrate such reference cells.

6.1.2 The calibration constant, C_R , of the reference cell shall be with respect to the reference spectral irradiance distribution of the desired RC (see 1.2).

6.1.3 A current measurement instrument (see 6.3) shall be used to determine the short-circuit current of the reference cell under the solar simulator.

6.1.4 *Special Case*—If the test cell also qualifies as a reference cell in that its I_{SC} or calibration constant at the RC is known prior to test, the test cell may be used to measure irradiance by itself and the separate reference cell omitted. The self-irradiance measurement technique is typically used to determine the fill factor of a reference cell post-calibration, and as a check for damage or degradation.

6.2 *Test Fixture*—Both the test cell and the reference cell are mounted in a fixture that meets the following requirements:

6.2.1 The test fixture shall ensure a uniform lateral temperature distribution to within $\pm 0.5^\circ\text{C}$ during the performance measurement.

6.2.2 The test fixture shall include a provision for maintaining a constant cell temperature for both the reference cell and the test cell (see 7.11).

NOTE 2—When using pulsed or shuttered solar simulators, it is possible that the cell temperature will increase upon initial illumination, even when the cell temperature is controlled.

6.2.3 The test fixture, when placed in the solar simulator, shall ensure that the fields-of-view of both the reference cell and the test cell are identical.

NOTE 3—Some solar simulators may have significant amounts of irradiation from oblique or non-perpendicular angles to the test plane. In these cases, it is important that the test cell and the reference cell have similar reflectance and angular-response characteristics.

6.2.4 A four-terminal connection (also known as a Kelvin connection, see Fig. 1) from the test cell to the I-V measure-

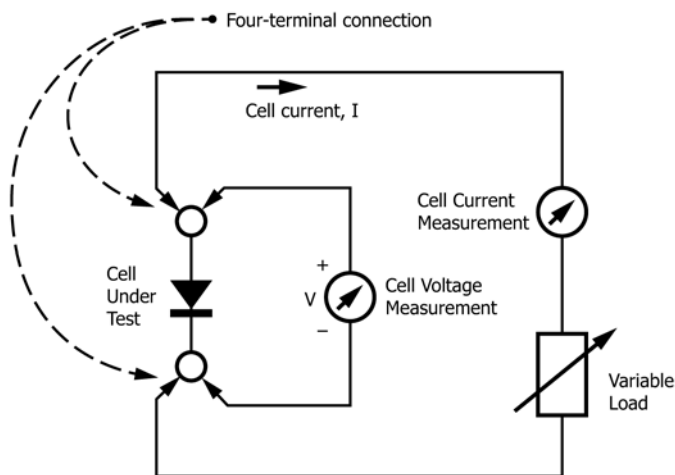


FIG. 1 I-V Measurement Schematic

ment instrumentation (see 6.3 – 6.5) shall be used.

6.3 *Current Measurement Equipment*—Electrical instrumentation used to measure the current through the test cell during the performance measurement. The instrumentation shall have a resolution of at least 0.02 % of the maximum current encountered, and shall have a total error of less than 0.1 % of the maximum current encountered.

6.3.1 The current measurement equipment shall measure data points simultaneously with the voltage (see 6.4) and short-circuit current (see 6.9) measurement equipment, to within 10 μs .

6.4 *Voltage Measurement Equipment*—Electrical instrumentation used to measure the voltage across the test cell during the performance measurement. The instrumentation shall have a resolution of at least 0.02 % of the maximum voltage encountered, and shall have a total error of less than 0.1 % of the maximum voltage encountered.

6.4.1 The voltage measurement equipment shall measure data points simultaneously with the current (see 6.3) and short-circuit current (see 6.9) measurement equipment, to within 10 μs .

6.5 *Variable Load*—An electronic load, such as a variable resistor or a programmable power supply, used to operate the test cell at different points along its I-V characteristic.

6.5.1 The variable load shall be capable of operating the test cell at an I-V point where the voltage is within 1 % of V_{OC} in the power-producing quadrant.

6.5.2 The variable load shall be capable of operating the test cell at an I-V point where the current is within 1 % of I_{sc} in the power-producing quadrant.

6.5.3 The variable load shall allow an output power (the product of cell current and cell voltage) resolution of at least 0.2 % of P_{MP} .

6.5.4 The electrical response time of the variable load shall be fast enough to sweep the range of I-V operating points during the measurement period.

NOTE 4—It is possible that the response time of the test cell may limit how fast the range of I-V operating points can be swept, especially when pulsed solar simulators are used. For these cases, it may be necessary to measure smaller ranges of the I-V curve using multiple measurements to obtain the entire range required.

6.6 *Solar Simulator*—Requirements of the solar simulator used to illuminate the test cell are defined in Specification E927 (terrestrial applications) and Practice E491 (space applications).

6.6.1 The effective irradiance during the performance measurement shall be within $\pm 2\%$ of the RC value.

NOTE 5—This tolerance is a reasonable choice for SRC. For very low irradiance measurements, a tighter tolerance on the effective irradiance may be required because of the increased dependence of V_{OC} on irradiance.

6.7 *Temperature Measurement Equipment*—Instrumentation used to measure the cell temperatures of the reference cell, the test cell, and the monitor cell shall have a resolution of at least 0.2 $^\circ\text{C}$, and shall have a total uncertainty of less than $\pm 1^\circ\text{C}$ of reading.

6.7.1 Sensors used for the temperature measurement(s) shall be located in a position that minimizes any temperature gradients between the sensor and the photovoltaic device junction.

6.7.2 Time constants associated with these measurements shall be less than 500 ms.

6.8 *Monitor Cell (optional)*—An uncalibrated photovoltaic solar cell that is positioned in the test plane such that it is illuminated by the solar simulator during the performance measurement of the test cell. The monitor cell is used to measure the effective irradiance during the performance measurement following a transfer-of-calibration procedure from the reference cell. It is also used to correct current measurement data points of the test cell for temporal instability of the solar simulator.

6.8.1 The monitor cell may be positioned anywhere in the test plane of the solar simulator, but shall not be moved after the transfer-of-calibration procedure has been performed. Placement locations close to the test cell may be preferable.

6.8.2 The spectral responsivity of the monitor cell is unimportant, but the wavelength range of its responsivity should include that of the test cell. Crystalline-Si solar cells are recommended.

6.8.3 The monitor cell shall be mounted on a test fixture that controls its cell temperature to within its temperature measurement resolution during the performance measurement. It is recommended that the monitor cell have its own test fixture.

6.8.4 The time constant of the monitor cell's temperature measurement shall be less than 500 ms.

6.8.5 The short-circuit current of the monitor cell, as a property of the cell, shall not increase or decrease for the duration of the performance measurement, to within the resolution of the short-circuit current measurement equipment (see 6.9).

6.8.6 The monitor cell shall be checked at least annually for sufficient performance and stability.

6.9 *Short-Circuit Current Measurement Equipment*—Instrumentation used to measure the short-circuit current of the reference cell and the monitor cell.

6.9.1 The short-circuit current measurement equipment shall hold the voltage across these cells to within 25 mV of zero.

6.9.2 The short-circuit current measurement equipment shall measure current data points simultaneously with the current (see 6.3) and voltage (6.4) measurement equipment, to within 10 μ s.

7. Procedure

7.1 Measure the test cell area, A , using the definition of **area, photovoltaic cell** in Terminology E772.

7.2 Determine short-circuit current of the reference cell at the RC using:

$$I_{SC,R0} = C_R E_0 \quad (1)$$

7.3 Determine the spectral parameter, M , using Test Method E973, as follows:

7.3.1 Test Method E973 requires four spectral quantities: the spectral responsivities (or quantum efficiencies) of the test cell and the reference cell, the spectral irradiance distribution of the solar simulator, and the reference spectral irradiance distribution.

7.3.2 Two of these quantities will be known prior to the performance measurement: the reference cell spectral responsivity at its calibration temperature (that is, T_R , required as part of its calibration data) and the reference spectral irradiance distribution (selected or specified beforehand in 1.2).

7.3.3 Determine the quantum efficiency of the test cell at the temperature corresponding to the selected RC (that is, T) according to 7.4 of Test Method E973.

7.3.4 Measure the spectral irradiance distribution of the solar simulator according to 7.5 of Test Method E973. The measurement should be performed within the last 50 h of lamp time unless the spectral stability of the solar simulator has demonstrated that a longer period causes no discernible error.

7.3.5 *Special Case*—For the special case of 6.1.4, M is equal to one by definition if the test cell is within ± 1 °C of temperature at which its I_{SC} was calibrated; in this case the spectral measurements in 7.3.3 and 7.3.4 are not necessary and may be omitted.

7.3.6 Notice that in Test Method E973, T and T_R may not be equal to each other, and are not required to be so. Also, because both cells are required to be held within ± 1 °C of these temperatures (see 7.9.2.1 and 7.9.5.1), the temperature-dependent quantum efficiency terms for M in Test Method E973 may be omitted.

7.4 Determine the current correction factor due to spatial non-uniformity of irradiance, S , as follows:

7.4.1 For the special case of 6.1.4 in which the test cell is also the reference cell, set S equal to one and proceed to 7.5.

7.4.2 Obtain the area of the reference cell, A_R , either by measurement or from its calibration report.

7.4.3 Select the larger of A and A_R , and divide it by the smaller area. If this ratio is less than 3, set S equal to one and proceed to 7.5.

7.4.4 Use the procedure in Annex A2 to measure and compute S .

7.5 Mount the reference cell in the test fixture. Connect it to the short-circuit current measurement equipment, and illuminate it with the solar simulator.

7.5.1 For the special case of 6.1.4, the test cell is also the reference cell, thus $I_{SC,R}$ is equal to I_{SC} of the test cell throughout the remainder of the procedure.

7.6 *Solar Simulator with Adjustable Effective Radiance*—While measuring $I_{SC,R}$, adjust the effective irradiance so that $I_{SC,R}$ is equal to the reference cell's calibrated short-circuit current corrected for spatial non-uniformity of irradiance and spectral mismatch, that is,

$$I_{SC,R} = \frac{S}{M} I_{SC,R0} \quad (2)$$

7.6.1 Note that this adjustment can affect the eventual satisfaction of the provision in 6.6.1.

7.7 Measure the temperature of the reference cell, T_R .

7.7.1 T_R shall be within ± 1 °C of the reference cell's calibration temperature, including temperature measurement uncertainty.

7.8 *Stable Solar Simulator*—If the temporal instability of the solar simulator (as defined in Specification E927) is less than 0.1 %, the effective irradiance may be determined with the reference cell prior to the performance measurement. In this case, use the following steps to measure the effective irradiance and the I-V characteristic. Otherwise, proceed to 7.9.

NOTE 6—The reference cell's short-circuit current is a convenient way to verify the temporal instability of the solar simulator.

7.8.1 Measure the short-circuit current of the reference cell, $I_{SC,R}$, using the short-circuit current measurement equipment.

7.8.1.1 For the special case of 6.1.4, connect the test cell to the variable load and proceed to 7.8.4.

7.8.2 Replace the reference cell with the test cell.

7.8.3 Measure the temperature of the test cell, T .

7.8.3.1 T shall be within ± 1 °C of the applicable RC, including temperature measurement uncertainty.

7.8.4 Measure the I-V characteristic of the test cell by changing the operating point with the variable load so that the provisions of 6.5.1 – 6.5.3 are met. At each operating point on the I-V characteristic, simultaneously measure the test-cell voltage, (V), and test-cell current, (I), to within 10 μ s.

7.8.5 *Optional*—Connect the test cell to the short-circuit current measurement equipment and measure its I_{SC} .

7.8.6 Proceed to 7.10.

7.9 *Unstable Solar Simulator*:

7.9.1 Mount the monitor cell in its test fixture and connect it to the short-circuit current measurement equipment.

7.9.2 *Transfer Calibration*:

7.9.2.1 Measure the short-circuit currents of the reference cell and the monitor cell simultaneously within 10 μ s.

7.9.2.2 Repeat 7.9.2.1 a minimum of 10 times. The number of repetitions will vary according to the temporal instability of the solar simulator, and judgment should be used to establish the time needed for the transfer calibration.

7.9.2.3 Calculate the transfer calibration ratio using the following equation, where n is the number of repetitions:

$$C_T = \frac{1}{n} \sum_{i=1}^n \frac{I_{SC,R_i}}{I_{SC,M_i}} \quad (3)$$

7.9.3 For the special case of 6.1.4, proceed to 7.9.6.

7.9.4 Replace the reference cell with the test cell.

7.9.5 Measure the temperature of the test cell, T .

7.9.5.1 T shall be within ± 1 °C of the applicable RC, including temperature uncertainty.

7.9.6 Measure the I-V characteristic of the test cell by changing the operating point with the variable load so that the provisions of 6.5.1 – 6.5.3 are met. At each operating point on the I-V characteristic, simultaneously measure the test-cell voltage, (V), test-cell current, (I), and the monitor cell short-circuit current ($I_{SC,M}$) to within 10 μ s.

7.10 Measure the temperature of the test cell to verify that it is still within ± 1 °C of the applicable RC, including temperature uncertainty.

7.11 *Optional*—Disconnect the variable load and measure the voltage across the test cell. With no current flowing through the cell, this voltage is the open-circuit voltage, V_{OC} . This measurement may also be performed prior to 7.8.4 or 7.9.6.

7.12 *Optional*—Determine the series resistance, R_S , of the test cell. An acceptable method is described in Annex A1.

7.13 Remove the test cell from the test fixture.

8. Calculation of Results

8.1 Determine the short-circuit current of the reference cell, $I_{SC,R}$, as follows:

8.1.1 *Stable Solar Simulator*—Use the reference cell short-circuit current measured prior to the I-V curve sweep (see 7.8.1).

8.1.2 *Unstable Solar Simulator*—Compute values of $I_{SC,R}$ from the monitor cell short-current values, $I_{SC,M}$, measured with each I-V data pair (see 7.9.6).

$$I_{SC,R} = C_T I_{SC,M} \quad (4)$$

8.2 Calculate the test cell current and voltage at RC from the measured I-V curve data pairs and the value or values of $I_{SC,R}$ from 8.1).

$$I_0 = \frac{S}{M} \frac{I_{SC,R0}}{I_{SC,R}} I, \quad V_0 = V \quad (5)$$

8.3 Form an ordered set of test cell current-voltage-power data points from each I_0 - V_0 data pair, sorted from lowest to highest V_0 , with the j th element as:

$$U_0[j] = \{ I_0, V_0, P_0 \} = \{ I_0, V_0, I_0 \cdot V_0 \} \quad (6)$$

8.4 Determine the short-circuit current I_{SC} , using one of the following procedures:

8.4.1 Calculate the short-circuit current from I_0 - V_0 data pairs in U_0 where V_0 is close to zero using a 1st degree polynomial (straight-line) interpolation or least-squares regression.

8.4.1.1 Higher-degree polynomials may be preferable if there is significant curvature in the I-V curve near $V_0=0$.

8.4.2 If the optional measurement of 7.8.5 was performed, use this value of I_{SC} .

8.5 Determine the open-circuit voltage V_{OC} using one of the following procedures:

8.5.1 Calculate the open-circuit voltage from I_0 - V_0 data pairs in U_0 where I_0 is close to zero using a 1st degree polynomial (straight-line) interpolation or least-squares regression.

8.5.1.1 Higher-degree polynomials may be preferable if there is significant curvature in the I-V curve near $I_0=0$.

8.5.2 If the optional no-load measurement of 7.11 was performed, use this value of V_{OC} .

8.6 Determine the cell maximum power P_{MP} , as follows:

8.6.1 Select the elements in U_0 with the largest P_0 and designate the data points of this element as I_{MP} , V_{MP} , and P_{MP} .

8.6.2 Due to random fluctuations the probability will be high that the element selected in 8.6.1 is not the best representation of the maximum power, and it is common for P_{MP} to be too large. It is recommended that regression be used to obtain

a better estimation of the maximum power, as follows. If the regression procedure is not used, then designate $I_{MP}=I_{MP}$, $V_{MP}=V_{MP}$, and $P_{MP}=P_{MP}$, and proceed to 8.7.

8.6.2.1 Select a subset of U_0 that consists of all elements that are within the following range (the 0.85 value is for general guidance and can be adjusted as needed according to the number of data points in U_0).

$$P_0 \geq 0.85P_{MP} \quad (7)$$

8.6.2.2 Perform a fourth-order least-square regression to the P_0 versus V_0 data selected in 8.6.2.1. The order of the polynomial regression may be adjusted as needed. Test cells with higher fill factors ($\geq 76\%$) typically need more data points and higher order regressions to fit a polynomial through the maximum power point.

8.6.2.3 Calculate the derivative polynomial of the polynomial obtained from 8.6.2.2.

8.6.2.4 Find the root of the derivative polynomial obtained from 8.6.2.3 using V_{MP} as an initial guess. An appropriate procedure is the Newton-Horner method with deflation.³ The root is V_{MP} .

8.6.2.5 Calculate P_{MP} by substituting V_{MP} into the original polynomial from 8.6.2.2.

8.6.2.6 Calculate $I_{MP}=P_{MP}/V_{MP}$.

8.6.2.7 Construct a plot of P_0 versus V_0 for the data selected in 8.6.1; add to this plot the curve corresponding to the polynomial obtained in 8.6.2.2, and indicate the point corresponding to (P_{MP}, V_{MP}) . Use this plot to visually confirm the validity of the regression result.

8.7 Calculate the fill factor in percent, FF , using the following equation:

$$FF = 100\% \cdot \frac{P_{MP}}{I_{sc}V_{oc}} \quad (8)$$

8.8 Calculate the efficiency in percent, η , using the following equation:

$$\eta = 100\% \cdot \frac{P_{MP}}{AE_0} \quad (9)$$

9. Report

9.1 The end user ultimately determines the amount of information to be reported. Listed in 9.2 – 9.5.8 are the minimum, mandatory reporting requirements.

9.2 Test Cell Description:

9.2.1 Identification,

9.2.2 Physical description,

9.2.3 Area, A , as determined in 7.1,

9.2.4 Series resistance, R_s , if measured (see 7.12), and

9.2.5 Quantum efficiency, in plotted and tabular form, as determined for spectral mismatch parameter calculation (see 7.3.3).

9.3 Reference Cell Description:

9.3.1 Identification,

9.3.2 Physical description,

9.3.3 Calibration laboratory,

9.3.4 Calibration procedure (see 6.1.1),

9.3.5 Date of calibration,

9.3.6 Reference spectral irradiance distribution (see 5.4),

9.3.7 Quantum efficiency, in plotted and tabular form, as required for Test Method E973, and

9.3.8 Reference cell short-circuit current, $I_{sc,R0}$ (that is, its calibration value, from 7.2).

9.4 Test Conditions:

9.4.1 Description and classification of solar simulator,

9.4.2 Reporting conditions (RC): SRC (see Table 1) or user-specified conditions,

9.4.3 Date and time of test,

9.4.4 Spectral mismatch parameter, M (see 7.3),

9.4.5 Measured reference cell temperature, T_R (possibly a range), and

9.4.6 Measured test cell temperature, T (possibly a range).

9.5 Test Results:

9.5.1 Short-circuit current, I_{sc} ,

9.5.2 Open-circuit voltage, V_{oc} ,

9.5.3 Maximum power, P_{MP} ,

9.5.4 Voltage at maximum power, V_{MP} ,

9.5.5 Current at maximum power, I_{MP} ,

9.5.6 Fill factor, FF ,

9.5.7 Efficiency, η , and

9.5.8 characteristic, in plotted and tabular form.

10. Precision and Bias⁴

10.1 *Interlaboratory Test Program*—An interlaboratory study of cell performance measurements was conducted between 1992 and 1994. Six laboratories performed three repetitions on each of ten cells circulated among the participants. The design of the experiment, similar to that of Practice E691, and a within-between analysis of the data are given in ASTM Research Report No. RR:E44-1002.

10.2 *Test Result*—Because I-V measurements produce a table of current vs. voltage points rather than a single numeric result, the precision analysis was performed on the maximum power point data submitted by the participants. The precision information given below is in percentage points of the maximum power in watts.

10.3 Precision:

95 % repeatability limit (within-laboratory)

1.5 %

95 % reproducibility limit (between-laboratory)

7.1 %

10.4 *Bias*—The contribution of bias to the total error will depend upon the bias of each individual parameter used for the determination of the cell performance. However, it has been shown that the total bias is dominated by three sources: the reference cell calibration, spatial uniformity of the solar simulator, and the total area measurement.⁵ Bias contributions from instrumentation tend to be, at most, a few tenths of a

⁴ Supporting data have been filed at ASTM International Headquarters and may be obtained by requesting Research Report RR:E44-1002.

⁵ Emery, K. A., Osterwald, C. R., and Wells, C. V., "Uncertainty Analysis of Photovoltaic Efficiency Measurements," Proceedings of the 19th IEEE Photovoltaics Specialists Conference— 1987, Institute of Electrical and Electronics Engineers, New York, NY, pp. 153–159.

³ Burden, R. L., and Faires, J. D., Numerical Analysis, 3rd ed., Prindle, Weber & Schmidt, Boston, MA, 1985, p.42.

percent, while the bias from the three sources listed here can be as much as ten times greater if the bias is not minimized.

11. Keywords

11.1 cell; performance; photovoltaic; testing

ANNEXES

(Mandatory Information)

A1. METHOD OF DETERMINING THE SERIES RESISTANCE OF A PHOTOVOLTAIC DEVICE

A1.1 The series resistance R_s is determined from measurements of the I-V curve data at two different values of the effective irradiance while the temperature of the device is kept constant at approximately 25°C. Obtain two sets of I-V data from the device at two different levels of irradiance, for example, $E_1 = 800 \text{ Wm}^{-2}$ and $E_2 = 1200 \text{ Wm}^{-2}$ (these values are given only as an example and need not be established exactly). Temperature variations during the I-V curve measurements must be less than $\pm 1 \text{ }^\circ\text{C}$.

A1.2 At the two irradiance levels, E_1 and E_2 , the following values are extracted from the two I-V curves, as shown in Fig. A1.1:

A1.1:

Values at irradiances	E_1	E_2
Short-circuit current	I_{sc1}	I_{sc2}
Voltage at $I_1 = 0.9 I_{sc1}$	V_1	
Voltage at $I_2 = 0.9 I_{sc2}$		V_2

A1.3 From these data, R_s is calculated as follows:

$$R_s = (V_2 - V_1)/(I_1 - I_2) \tag{A1.1}$$

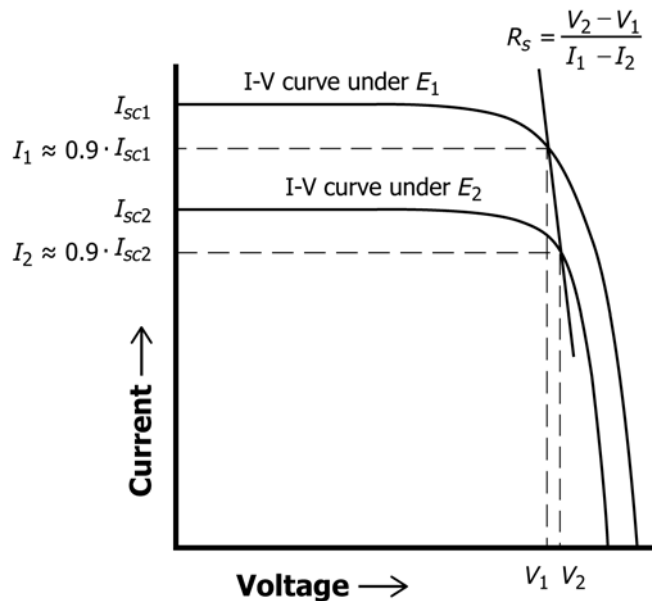


FIG. A1.1 Series Resistance Measurement

A2. METHOD OF DETERMINING THE CURRENT CORRECTION FACTOR DUE TO SPATIAL NON-UNIFORMITY OF IRRADIANCE

A2.1 The current correction factor due to spatial non-uniformity of irradiance, S , is defined as the average irradiance of the solar simulator over the area of the test cell to average irradiance over the area of the reference cell. These averages are determined through a mapping technique that consists of dividing the test plane into equally sized pixels and then measuring the relative irradiance at each pixel with a solar cell detector that has an area approximately equal to the area of one pixel.

A2.2 This mapping technique is similar to the procedure in 8.3 of Specification E927 for mapping solar simulator non-uniformity of spatial irradiance. The Specification E927 procedure, however, is generic and without regard to the size of any test devices. It requires a minimum of only 36 pixels (a 6×6 matrix) and a minimum detector area of 25 % of the pixel area. Thus, as much as 75 % of the solar simulator test plane area can be left out of the mapping. For these reasons the Specification E927 procedure is unsuitable for determinations of spatial non-uniformity correction factors.

A2.3 *Pixel Size*—The pixel size (A_P) shall be less than or equal to the smaller of A and A_R (see 7.1 and 7.4.2). The distance between adjacent pixels is then equal to $\sqrt{A_P}$.

A2.4 *Detector Size*—The area of the solar cell that will be used to map the spatial non-uniformity shall be within ± 25 % of A_P .

A2.4.1 It may be convenient to use either the test cell or the reference as the detector. In this case, A_P will be equal to A or A_R , and one pixel will completely contain the location where the smaller cell will be situated in the solar simulator.

A2.5 *Mapping Area*—The mapping area must include the entire location where the larger cell will be situated in the solar simulator. Divide this area into pixels according to A2.3.

A2.6 Place the detector into the solar simulator at the first pixel and connect it to the short-circuit current measurement equipment (see 6.9). Expose the detector to the light and keep its temperature constant; the exact temperature value is unimportant.

A2.7 Measure and record the I_{SC} of the detector. In an unstable solar simulator (see 7.8), it is necessary to correct for intensity fluctuations using a monitor solar cell (see 7.9). Because the mapping is a relative irradiance measurement, the transfer calibration procedure can be omitted and C_T assumed to be one.

A2.8 Move the detector to the next pixel location and repeat A2.7 until all pixels have been measured.

A2.9 *Peak Normalization*—Divide all pixel currents with the highest I_{SC} measured.

A2.10 Form an array that contains all currents from the pixels in which the test cell will be located, where n is the number of test cell pixels:

$$\mathbf{I}_T = [I_1, I_2, \dots, I_n] \quad (\text{A2.1})$$

A2.11 Form an array that contains all currents from the pixels in which the reference cell will be located, where m is the number of reference cell pixels:

$$\mathbf{I}_S = [I_1, I_2, \dots, I_m] \quad (\text{A2.2})$$

A2.12 Calculate the current correction factor due to spatial non-uniformity of irradiance using Eq A2.3:

$$S = \frac{\langle \mathbf{I}_T \rangle}{\langle \mathbf{I}_S \rangle} = \frac{\frac{1}{n} \sum_{i=1}^n I_{Ti}}{\frac{1}{m} \sum_{j=1}^m I_{Rj}} \quad (\text{A2.3})$$

A2.13 It is not necessary to perform the spatial non-uniformity mapping each time a test cell is measured. As long as the pixel size requirements are met and the non-uniformity does not change with time significantly, a previous mapping can be used simply by selecting the appropriate pixels. By using smaller pixels it will be easier to accommodate a variety of differing cell geometries, at the expense of a longer measurement time.

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